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First Named Inventor STATEMENT BY APPLICANT Paul A. Farrar Group Art Unit N/A (use as many sheets as necessary) Not Yet Assigned **Examiner Name** M4065.0392/P392 of 2 Attorney Docket Number

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Examiner Cite	Cite	U.S. Patent	Document	Name of Patentee or Applicant	Date of Publication of	Pages, Columns, Lines, Where Relevant
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